

0.03-4GHz 100W CW GaN Broadband RF SPDT Swich

Product Overview

The MCSDT0034P51 is a symmetrical reflective Single Pole double Throws \$P2TDswitch designed for broadband, high power switching applications. Its broadband behavior from 30MHz to 4.0GHz frequencies makes the MCSDT0034P51 an e¢cellent switch for all the applications requiring low insertion loss, high isolation and high linearitywithin a small package size. Part can also be used below 30MHz with reduced power handling.

The MCSDT0034P51 is packaged into a compact Quad Flat No lead QQFND5¢5mm 32 leads plastic package.

Applications

- Private mobile radio handsets
- Public safety handsets
- Cellular infrastructure
- LTE relays and micro-cells
- Satellite terminals
- Small cells

Key Features

• Operating frequency: 30MHz to 4GHz

• Low insertion loss: 0.2dB @ 1GHz

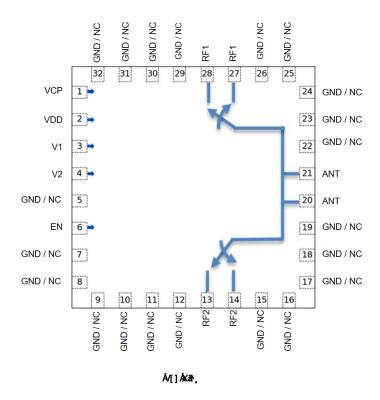
• High isolation: 40dB @ 1GHz

• 100W CW, 200W Peak Power

· No e¢ternal DC blocking capacitors on RF lines

• Xersatile 4.5-5.5X power supply

Functional Diagram



Ordering Information

Part No.	Description
MCSDT0034P51	30MHz-4GHz 100W CW GaN Broadband RF Switch SP2T, 1500pcs in one Ï ' Tape & Reel



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Signal Descriptions

Pin	Name	Description
1	VCP	When EN=1 or Floating, the VCP is internal charge pump voltage output. When EN=0, the VCP is Negative Voltage supply pin.
2	VDD	DC power supply
3	V1	Switch control input 1
4	V2	Switch control input 2
5,7,8,9,10,11,16,17,18, 23,24,25,30,31,32	GND/NC	No internal connection, Grounding can better achieve heat dissipation.
6	EN	Charge pump enable. When EN=0, internal charge pump is disabled and external -18V supply will be supplied to VCP pin. When EN=1 or Floating, internal charge pump is enabled and VCP pin should be floated.
12,15,19,22,26,29	NC	No internal connection
13,14	RF 2	RF port 2
20,21	ANT	Antenna port
27,28	RF 1	RF port 1
33	Ground	Ground thermal pad

Absolute Maximum Ratings@Ta = +25°C

Parameter	Symbol	Absolute Maximum	
Power Supply Voltage	VDD	4.5V to 5.5V	
Charge Pump Voltage	VCP	-20V to -17V	
RF Input Power peak	Ppeak	54dBm @ 1.3GHz	
RF Input Power CW	PCW	51dBm @ 1.3GHz	
Hot Switching Power CW	PHS	50dBm @ 1.3GHz	
Junction Temperature	Tj	+140 °C	
Operating Temperature	Тор	-40C to +100°C	
Storage Temperature	T _{st}	-55°C to +150°C	

Electrical Specifications@Ta = +25°C

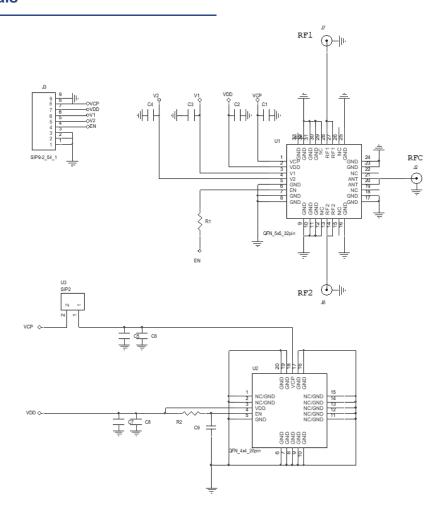
Parameter	Test condition	Min	Тур	Max	Unit
Operating Frequency		30		4000	MHz
	Freq=1GHz		0.2		dB
Insertion Loss,	Freq=2GHz		0.3		dB
ANT-RFx	Freq=3GHz		0.35		dB
	Freq=4GHz		0.4		dB
	Freq=1GHz		41		dB
Isolation,	Freq=2GHz		34		dB
ANT-RFx	Freq=3GHz		29		dB
	Freq=4GHz		25		dB
Detum Lana	Freq=1GHz		30		dB
Return Loss	Freq=2GHz		30		dB
ANT-RFx	Freq=3GHz		22		dB



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	Freq=4GHz		20		dB
P0.1 dB	1300MHz, CW	50			dBm
Peak P0.1 dB	1300MHz, 1% duty cycle, 1 mS period.		54		dBm
IIP3	Pin=30dBm/tone		75		dBm
Switching time	50% ctrl to 10/90% of the RF value is settled. C1=1nF		1		us
Control Voltage	Power supply VDD	4.5	5	5.5	V
	Negative Voltage supply, VCP	-20	-18	-17	V
	All control pins high, Vih	4.5	5	5.5	V
	All control pins low, Vil	-0.3	0	0.5	V
Control Current	All control pins low, lil				uA
	All control pins high, lih				uA
Current Consumption, IDD	Active mode		1	3.6	mA

Bill of Materials



Note:

When EN=0, internal charge pump is disabled and external -18V supply will be supplied to VCP pin. When EN=1 or Floating, internal charge pump is enabled and VCP pin should be floated.



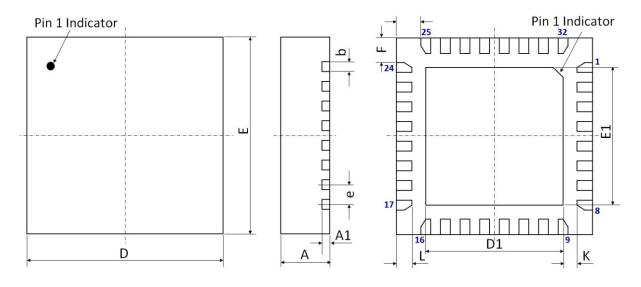
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Component	Description
U1	MCSDT0034P51
U2	MCNS6218
C1、C6、C8	1nF, 25 V, ±10%, 0402
C2、C5、C7、C9	1uF, 25 V, ±10%, 0402
C3、C4	100pF 25 V, ±10%, 0402
R1	0Ω, 0402
R2	500KΩ, ±10%, 0402

Bias Table

V1	V2	Active RF Path
0	0	ANT-RF1
1	0	ANT-RF2
0	1	ALL OFF
1	1	ALL OFF

Device Package Information



Device Package Dimensions

Dimension (mm)	Value (mm)	Tolerance (mm)	Dimension (mm)	Value (mm)	Tolerance (mm)
Α	0.85	±0.05	E	5.00 BSC	±0.05
A1	0.203	±0.02	E1	3.20	±0.06
b	0.25	+0.05/-0.07	F	0.625	±0.05
D	5.00 BSC	±0.05	G	0.625	±0.05
D1	3.20	±0.06	L	0.40	±0.05
е	0.50 BSC	±0.05	K	0.50	±0.05